

Electronic Patent Application Fee Transmittal

Application Number:	10849617			
Filing Date:	20-May-2004			
Title of Invention:	Methods of fabricating nitride-based transistors having regrown ohmic contact regions and nitride-based transistors having regrown ohmic contact regions			
First Named Inventor/Applicant Name:	Adam William Saxler			
Filer:	Elizabeth A. Stanek/Erin Dutton			
Attorney Docket Number:	5308-413			
Filed as Large Entity				
Utility Filing Fees				
Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Basic Filing:				
Pages:				
Claims:				
Miscellaneous-Filing:				
Petition:				
Patent-Appeals-and-Interference:				
Notice of appeal	1401	1	500	500
Post-Allowance-and-Post-Issuance:				
Extension-of-Time:				

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Miscellaneous:				
Total in USD (\$)				500